

# 600V High voltage High & Low-side, Gate Driver

## BS2101F

#### **General Description**

The BS2101F is a monolithic high and low side gate drive IC, which can drive high speed power MOSFET and IGBT driver with bootstrap operation.

The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates up to 600V.

The logic inputs can be used 3.3V and 5.0V.

The Under Voltage Lockout (UVLO) circuit prevents malfunction when VCC and VBS are lower than the specified threshold voltage.

#### Features

- Floating Channels for Bootstrap Operation to +600V
- Gate drive supply range from 10V to 18V
- Built-in Under Voltage Lockout for Both Channels
- 3.3V and 5.0V Input Logic Compatible
- Matched Propagation Delay for Both Channels
- Output in phase with input

#### Applications

MOSFET and IGBT high side driver applications

#### Key Specifications

- High-side floating supply voltage:
- Output voltage range:
- Min Output Current lo+/lo-:
- Turn-on/off time:
- Delay Matching:
- Offset supply leakage current:
- Operating temperature range:
  - Operating temperature range.

#### Package SOP-8

W(Typ) x D(Typ) x H(Max) 5.00mm x 6.20mm x 1.71mm

600V

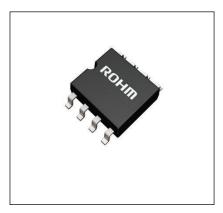
10V to 18V 60mA/130mA

220ns(Typ)

50ns(Max)

50µA (Max)

-40°C to +125°C



#### **Typical Application Circuits**

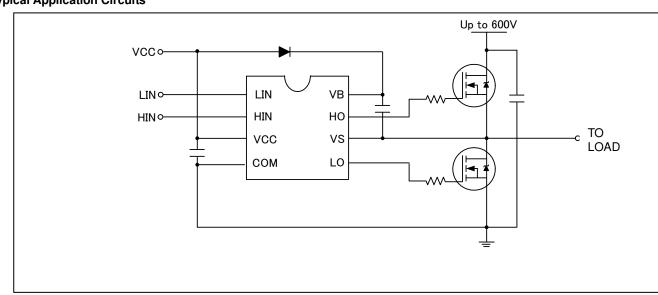


Figure 1. Typical Application Circuit

OProduct structure : Silicon monolithic integrated circuit OThis product has no designed protection against radioactive rays

## Pin Configuration

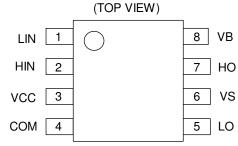


Figure 2. Pin Configuration

#### **Pin Description**

Pin No.	Symbol	Function		
1	LIN	Logic input for low side gate driver output		
2	HIN	Logic input for high side gate driver output		
3	VCC	Low side supply voltage		
4	COM	Low side return		
5	LO	Low side gate drive output		
6	VS	High side floating supply return		
7	НО	High side gate drive output		
8	VB	High side floating supply		

#### **Block Diagram**

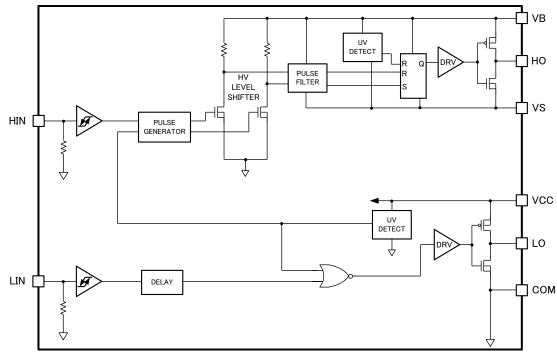


Figure 3. Functional Block Diagram

#### Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Min	Max	Unit
High side offset voltage	Vs	V <sub>B</sub> -20	V <sub>B</sub> +0.3	V
High side floating supply voltage	V <sub>B</sub>	-0.3	+620	V
High side floating output voltage HO	V <sub>HO</sub>	V <sub>S</sub> -0.3	V <sub>B</sub> +0.3	V
Low side and logic fixed supply voltage	V <sub>CC</sub>	-0.3	+20	V
Low side output voltage LO	V <sub>LO</sub>	-0.3	V <sub>CC</sub> +0.3	V
Logic input voltage (HIN, LIN)	V <sub>IN</sub>	-0.3	V <sub>CC</sub> +0.3	V
Logic ground	Com	V <sub>CC</sub> -20	V <sub>CC</sub> +0.3	V
Allowable offset voltage SLEW RATE	dV <sub>S</sub> /dt	-	50	V/ns
Junction temperature	Tjmax	-	150	°C
Storage temperature	Tstg	-55	+150	°C

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

## Thermal Resistance<sup>(Note 1)</sup>

Parameter	Symbol	Thermal Resistance (Typ)     1s <sup>(Note 3)</sup> 2s2p <sup>(Note 4)</sup>		Unit	
SOP-8			- F		
Junction to Ambient	$\theta_{JA}$	197.4	109.8	°C/W	
Junction to Top Characterization Parameter <sup>(Note 2)</sup>	$\Psi_{JT}$	21	19	°C/W	
(Note 1)Based on JESD51-2A(Still-Air)	J			1	

(Note 2)The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package. (Note 3)Using a PCB board based on JESD51-3.

(Note b) baild based on the board based on the						
Material	Board Size					
FR-4	114.3mm x 76.2mm x 1.57mmt					
Thickness						
70µm						
	Material FR-4 Thickness					

(Note 4)Using a PCB board based on JESD51-7.

Layer Number of Measurement Board	Material	Board Size			
4 Layers	FR-4	114.3mm x 76.2mm x 1.6mmt			
Тор		2 Internal Layers		Bottom	
Copper Pattern	Thickness	Copper Pattern Thickness		Copper Pattern	Thickness
Footprints and Traces	70µm	74.2mm x 74.2mm	35µm	74.2mm x 74.2mm	70µm

## **Recommended Operating Ratings**

Parameter	Symbol	Mln	Max	Unit
High side floating supply voltage	VB	V <sub>S</sub> +10	V <sub>S</sub> +18	V
High side floating supply offset voltage	$V_{S}$	-	600	V
High side (HO) output voltage	V <sub>HO</sub>	Vs	V <sub>B</sub>	V
Low side (LO) output voltage	$V_{LO}$	Com	V <sub>CC</sub>	V
Logic input voltage (HIN, LIN)	V <sub>IN</sub>	Com	V <sub>CC</sub>	V
Low side supply voltage	V <sub>CC</sub>	10	18	V
Ambient temperature	T <sub>A</sub>	-40	+125	°C

## **DC Operation Electrical Characteristics**

(Unless otherwise specified: Ta=25°C,  $V_{CC}$ =15V,  $V_{BS}$ =15V,  $V_{S}$ =COM,  $C_{L}$ =1000pF)

Parameter	Symbol Limits		Unit	Conditions		
Farameter	Symbol	Min	Тур	Max	Unit	Conditions
$V_{\text{CC}}$ and $V_{\text{BS}}$ supply undervoltage positive going threshold	V <sub>CCUV+</sub> V <sub>BSUV+</sub>	8	8.9	9.8		
$V_{\text{CC}}$ and $V_{\text{BS}}$ supply undervoltage negative going threshold	V <sub>CCUV-</sub> V <sub>BSUV-</sub>	7.4	8.2	9	V	
V <sub>cc</sub> supply undervoltage lockout hysteresis	V <sub>CCUVH</sub> V <sub>BSUVH</sub>	0.3	0.7	-		
Offset supply leakage current	I <sub>LK</sub>	-	-	50		$V_B = V_S = 600V$
Quiescent $V_{BS}$ supply current	I <sub>QBS</sub>	20	60	150	μA	$V_{IN} = 0V \text{ or } 5V$
Quiescent $V_{CC}$ supply current	lacc	50	120	240		$V_{IN} = 0V \text{ or } 5V$
Logic "1" input voltage	V <sub>IH</sub>	2.6	-	-		
Logic "0" input voltage	V <sub>IL</sub>	-	-	1.0	v	
High level output voltage, $V_{\text{CC}}\left(V_{\text{BS}}\right)$ - $V_{\text{O}}$	V <sub>OH</sub>	-	-	2.8	v	
Low level output voltage, $V_{\rm O}$	V <sub>OL</sub>			1.2		I <sub>0</sub> = 20mA
Logic "1" input bias current	I <sub>IN+</sub>	-	5	40		$V_{IN} = 5V$
Logic "0" input bias current	I <sub>IN-</sub>	-	1.0	2.0	- μΑ	V <sub>IN</sub> = 0V
Output high short circuit pulse current	I <sub>O+</sub>	60	-	-		V <sub>O</sub> = 0V Pulse Width≦10µs
Output low short circuit pulsed current	I <sub>O-</sub>	130	-	-	- mA	V <sub>O</sub> = 15V Pulse Width≦10µs

## **AC Operation Electrical Characteristics**

(Unless otherwise specified: Ta=25°C,  $V_{CC}$ =15V,  $V_{BS}$ =15V,  $V_{S}$ =COM,  $C_{L}$ =1000pF)

Parameter	Symbol		Limits			Conditions
Farameter	Symbol	Min	Тур	Max	Unit	Conditions
Turn-on propagation delay	t <sub>on</sub>	120	220	320		$V_{S} = 0V$
Turn-off propagation delay	t <sub>off</sub>	130	220	330	ns	$V_{\rm S} = 0V \text{ or } 600V$
Turn-on rise time	tr	60	200	300	115	
Turn-off fall time	t <sub>f</sub>	20	100	170		

(Unless otherwise specified: Ta=25°C,  $V_{CC}$ =15V,  $V_{BS}$ =15V,  $V_{S}$ =COM,  $C_{L}$ =1000pF)

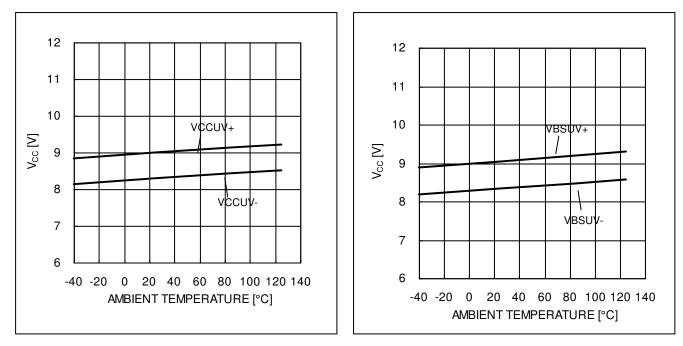
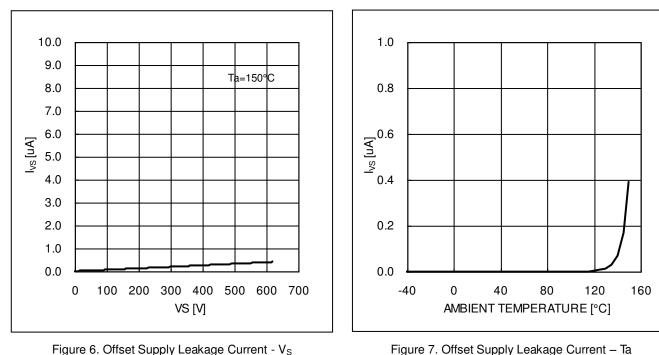
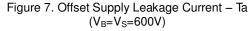


Figure 4. V<sub>CC</sub> UVLO - Ta

 $(V_B = V_S)$ 

Figure 5. V<sub>BS</sub> UVLO - Ta





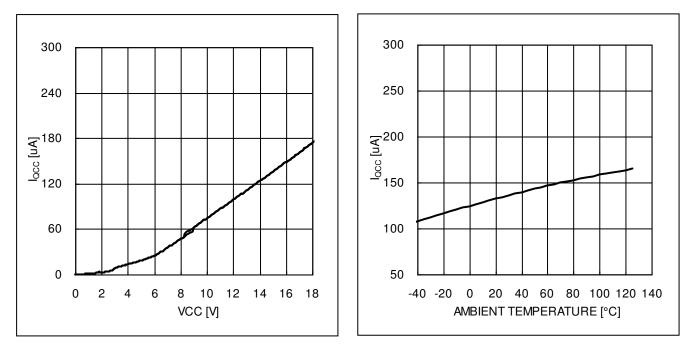
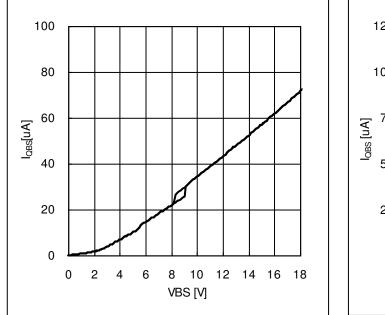
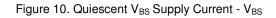
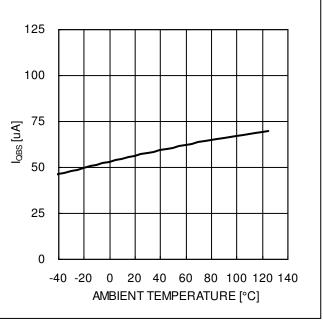


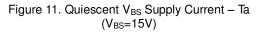
Figure 8. Quiescent V<sub>CC</sub> Supply Current - V<sub>CC</sub>

Figure 9. Quiescent V<sub>CC</sub> Supply Current – Ta  $(V_{CC}=15V)$ 









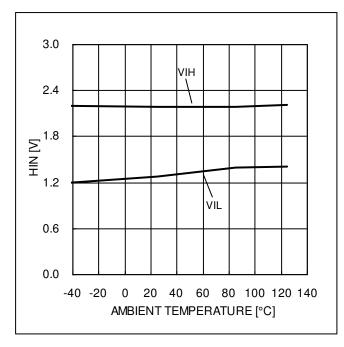
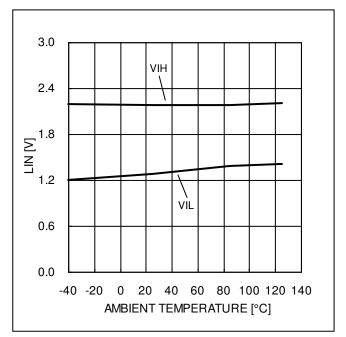
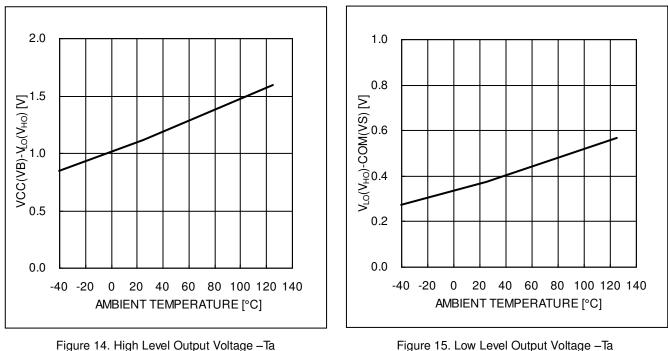


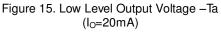
Figure 12. HIN Input Threshold Voltage - Ta







(I<sub>O</sub>=20mA)



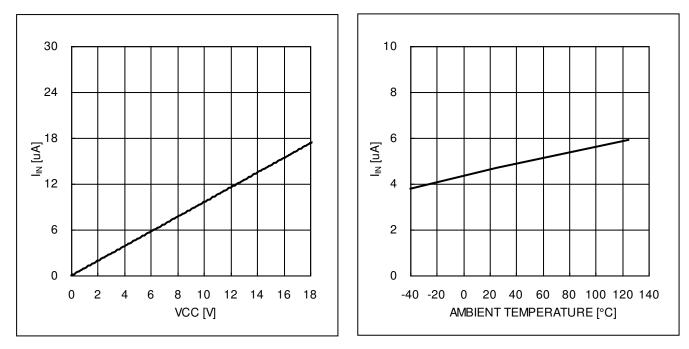


Figure 16. Input Bias Current - VIN

Figure 17. Input Bias Current – Ta (VIN=5V)

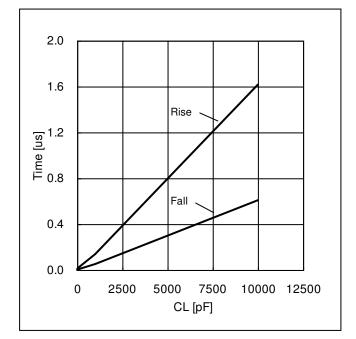


Figure 18. LO Rise/Fall time - Load Capacitance

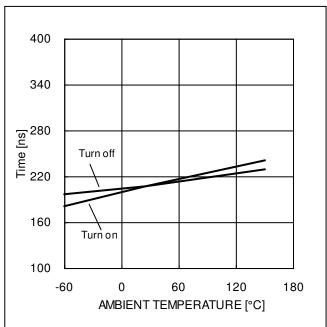


Figure 19.LO Turn on/off Propagation Delay -Ta

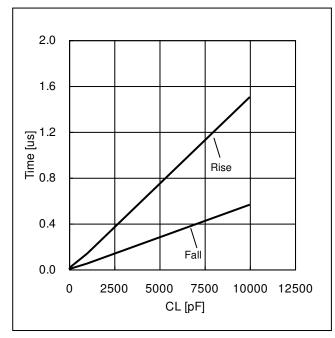


Figure 20. HO Rise/Fall time - Load Capacitance

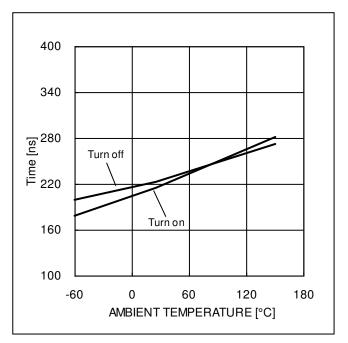
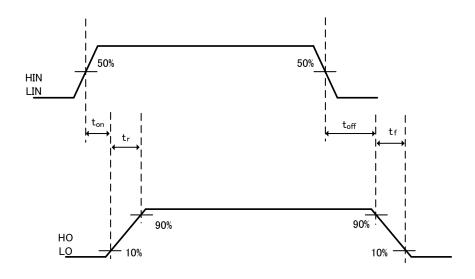


Figure 21. .HO Turn on/off Propagation Delay -Ta

## Truth table

Inj	out	Output		
LIN HIN		LO	НО	
L	L	L	L	
н	L	Н	L	
L	Н	L	Н	
Н	Н	Н	Н	

## **Timing Chart**





Cgd

RG(on)

١.

## **Application Components Selection Method**

- (1) Gate Resistor
  - The gate resistor  $R_{G(on/off)}$  is selected to control the switching speed of the output transistor. The switching time (t<sub>SW</sub>) is defined as the time spent to reach the end of the plateau voltage, so the turn on gate resistor  $R_{G(on)}$  can be calculated using the following formulas.

$$I_g = \frac{Q_{gs} + Q_{gd}}{t_{SW}} \tag{1}$$

$$R_{TOTAL(on)} = R_{pon} + R_{G(on)} = \frac{V_{BS} - V_{gs(th)}}{I_g}$$
(2)

$$t_{sw} = \frac{Q_{gs} + Q_{gd}}{I_g} = \frac{(Q_{gs} + Q_{gd})(R_{pon} + R_{G(on)})}{(V_{BS} - V_{gs(th)})}$$

Turn on gate resistor value can be changed to control output slope (dVs/dt). While the output voltage is non-linear, the maximum output slope should have a value near that of the following formula:

$$\frac{\mathrm{dVs}}{\mathrm{dt}} = \frac{\mathrm{I_g}}{\mathrm{C_{rss}}} \tag{4}$$

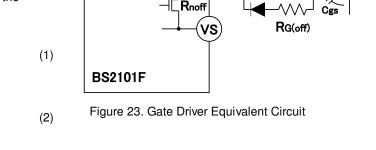
where:

C<sub>rss</sub> is the feedback capacitance.

Substituting the value of  $I_g$  from equation (2) into equation (4) yields the following formulas.

$$R_{TOTAL(on)} = R_{pon} + R_{G(on)} = \frac{V_{BS} - V_{gs(th)}}{C_{rss} \cdot \frac{dVs}{dt}}$$
(5)

$$R_{G(on)} = \frac{V_{BS} - V_{gs(th)}}{C_{rss} \cdot \frac{dVs}{dt}} - R_{pon}$$
(6)



VB

HC

⊣[Rpon

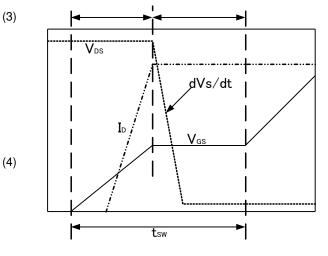


Figure 24. Gate Charge Transfer Characteristics

When the gate driver output is in off state, other dVs/dt may induce a drop in the gate voltage of the MOSFET, causing self-turn-on. To prevent this, please set up the turn off resistor ( $R_{G(off)}$ ) that satisfies the following formulas.

$$\mathbf{V}_{\mathrm{gs(th)}} \ge (\mathbf{R}_{\mathrm{noff}} + \mathbf{R}_{\mathrm{G(off)}}) \cdot \mathbf{I}_{\mathrm{g}} = (\mathbf{R}_{\mathrm{noff}} + \mathbf{R}_{\mathrm{G(off)}}) \cdot \mathbf{C}_{\mathrm{gd}} \frac{\mathrm{dVs}}{\mathrm{dt}} \quad (7)$$

$$\mathbf{R}_{G(off)} \leq \frac{\mathbf{V}_{gs(th)}}{\mathbf{C}_{gd}} \frac{\mathbf{d}\mathbf{Vs}}{\mathbf{dt}} - \mathbf{R}_{noff}$$
(8)

www.rohm.com © 2016 ROHM Co., Ltd. All rights reserved. TSZ22111 • 15 • 001

## BS2101F

(2) Bootstrap Capacitor C<sub>BS</sub>

To reduce ripple voltage, ceramic capacitors with low ESR value are recommended for use in the bootstrap circuit. The maximum voltage drop ( $\Delta V_{BS}$ ) that we have to guarantee when the high-side switch is in on state must be:

(9)

$$\Delta V_{BS} \leq VCC - VF - V_{GSMIN}$$

where:

VCC is the gate driver supply voltage, VF is the bootstrap diode forward voltage drop, and  $V_{\text{GSMN}}$  is the minimum gate-source voltage.

The total charge supplied (Q<sub>Total</sub>) by the bootstrap capacitor should have a value near the following formulas.

$$Q_{Total} = Q_G + (I_{LKGS} + I_{LK} + I_{LKDIO} + I_{QBS}) \cdot T_{HON}$$
(10)

where:

 $\begin{array}{l} Q_G \text{ is the total gate charge,} \\ I_{LKGS} \text{ is the switch gate-source leakage current,} \\ I_{LKDIO} \text{ is the bootstrap diode leakage current,} \\ I_{LK} \text{ is the level shifter circuit leakage current,} \\ I_{OBS} \text{ is the quiescent current, and} \\ T_{HON} \text{ is the high-side switch on time.} \end{array}$ 

The bootstrap capacitor value should satisfy the following formula.

$$C_{BS} \ge \frac{Q_{Total}}{\Delta V_{BS}} \tag{11}$$

However, BS2101F has a BSTUVLO function to prevent malfunction at low voltage between VB and VS.

Please ensure sufficient capacitor margin to prevent BSTUVLO malfunction.

It is not able to keep turning-on the same way as the high side switch driver because of the specifications of the bootstrap circuits.

In addition, it is recommended to insert a 1 µF ceramic capacitor between VB and VS. This capacitor should be placed as close as possible to these pins for noise reduction.

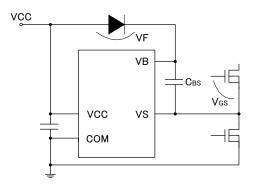


Figure 25. Bootstrap Power Supply Circuit

(3) Input Capacitor

Mount a low-ESR ceramic input capacitor near the VCC pin to reduce input ripple. For BS2101F, it is recommended to use a capacitor value two times larger than that of the bootstrap capacitor or more.

#### Power Dissipation

It is shown below reducing characteristics of power dissipation to mount 70mm × 70mm × 1.6mm<sup>t</sup>, 4layer PCB. Junction temperature must be designed not to exceed 150°C

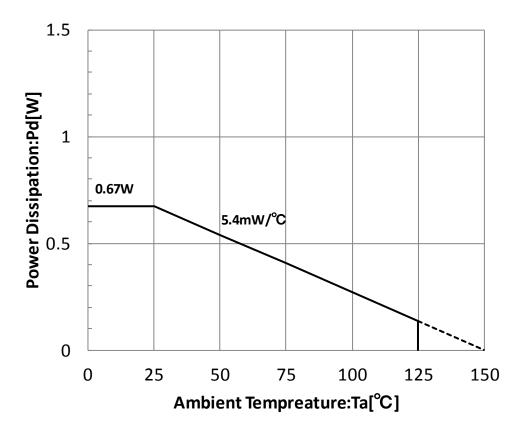


Figure 26. Power Dissipation(70mm × 70mm × 1.6mm<sup>t</sup> 4layer PCB)

## I/O Equivalence Circuits

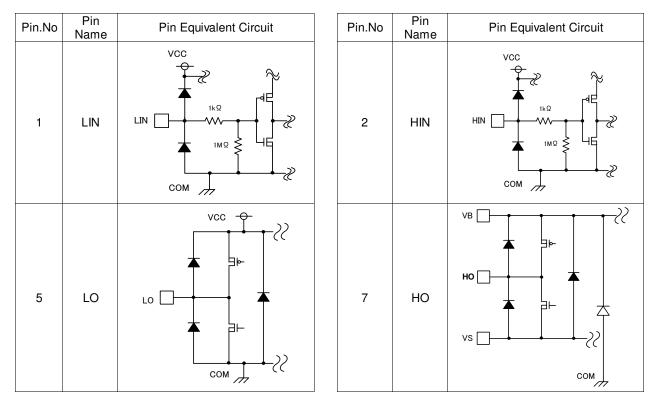


Figure 27. I/O Equivalent Circuit

## **Operational Notes**

#### 1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

#### 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

#### 3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

#### 4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

#### 5. Thermal Consideration

Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the maximum junction temperature rating.

#### 6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

#### 7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

#### 8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

#### 9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

#### 10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

#### 11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

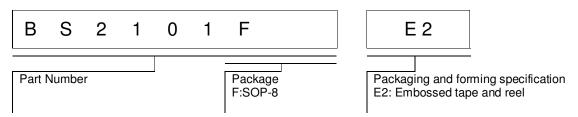
#### 12. Ceramic Capacitor

When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

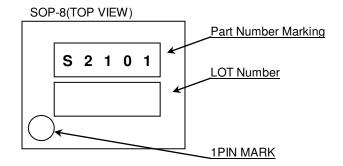
#### 13. Area of Safe Operation (ASO)

Operate the IC such that the output voltage, output current, and the maximum junction temperature rating are all within the Area of Safe Operation (ASO).

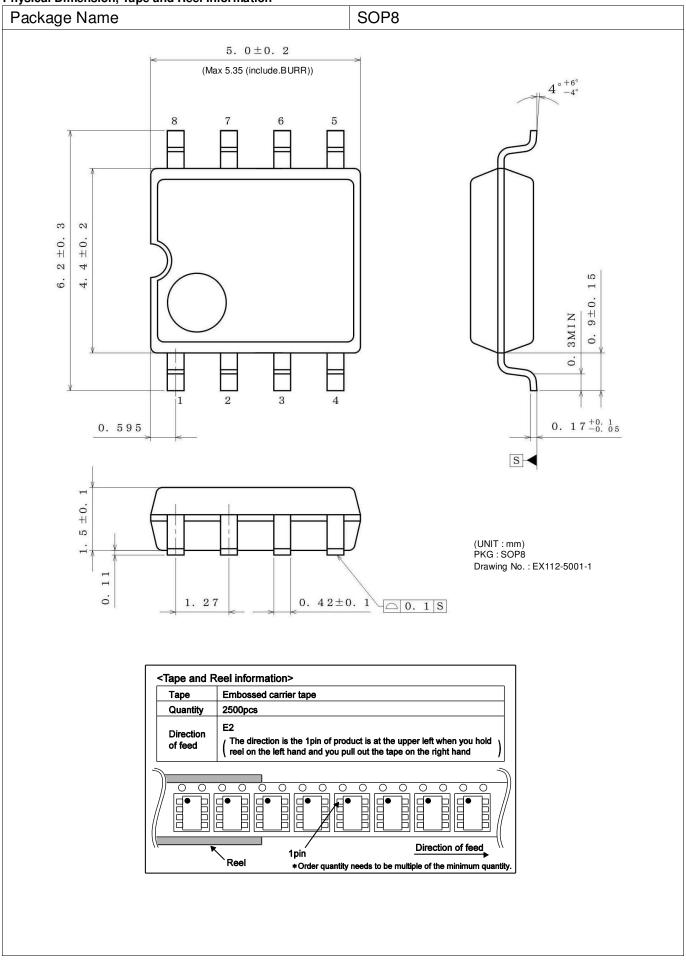
## **Ordering Information**



#### **Marking Diagrams**



#### Physical Dimension, Tape and Reel Information



## **Revision History**

Date	Revision	Changes
6.JAN.2016	001	New Release
2.JUN.2016	002	Correction of errors

## Notice

#### Precaution on using ROHM Products

1. Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment <sup>(Note 1)</sup>, transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

JAPAN	USA	EU	CHINA	
CLASSⅢ	CLASSⅢ	CLASS II b	CLASSII	
CLASSⅣ	CLASSII	CLASSⅢ	CLASSII	

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
  - [a] Installation of protection circuits or other protective devices to improve system safety
  - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
  - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

#### **Precautions Regarding Application Examples and External Circuits**

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

#### **Precaution for Product Label**

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

#### Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

#### Precaution for Foreign Exchange and Foreign Trade act

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

#### **Precaution Regarding Intellectual Property Rights**

- 1. All information and data including but not limited to application example contained in this document is for reference only. ROHM does not warrant that foregoing information or data will not infringe any intellectual property rights or any other rights of any third party regarding such information or data.
- 2. ROHM shall not have any obligations where the claims, actions or demands arising from the combination of the Products with other articles such as components, circuits, systems or external equipment (including software).
- 3. No license, expressly or implied, is granted hereby under any intellectual property rights or other rights of ROHM or any third parties with respect to the Products or the information contained in this document. Provided, however, that ROHM will not assert its intellectual property rights or other rights against you or your customers to the extent necessary to manufacture or sell products containing the Products, subject to the terms and conditions herein.

#### **Other Precaution**

- 1. This document may not be reprinted or reproduced, in whole or in part, without prior written consent of ROHM.
- 2. The Products may not be disassembled, converted, modified, reproduced or otherwise changed without prior written consent of ROHM.
- 3. In no event shall you use in any way whatsoever the Products and the related technical information contained in the Products or this document for any military purposes, including but not limited to, the development of mass-destruction weapons.
- 4. The proper names of companies or products described in this document are trademarks or registered trademarks of ROHM, its affiliated companies or third parties.

#### **General Precaution**

- 1. Before you use our Products, you are requested to care fully read this document and fully understand its contents. ROHM shall not be in an y way responsible or liable for failure, malfunction or accident arising from the use of a ny ROHM's Products against warning, caution or note contained in this document.
- 2. All information contained in this docume nt is current as of the issuing date and subject to change without any prior notice. Before purchasing or using ROHM's Products, please confirm the latest information with a ROHM sale s representative.
- 3. The information contained in this document is provided on an "as is" basis and ROHM does not warrant that all information contained in this document is accurate an d/or error-free. ROHM shall not be in an y way responsible or liable for any damages, expenses or losses incurred by you or third parties resulting from inaccuracy or errors of or concerning such information.

## **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Gate Drivers category:

Click to view products by ROHM manufacturer:

Other Similar products are found below :

00028
00053P0231
56956
57.404.7355.5
LT4936
57.904.0755.0
5882900001
00600P0005
00-9050-LRPP
00-9090-RDPP
5951900000

01-1003W-10/32-15
0131700000
00-2240
LTP70N06
LVP640
5J0-1000LG-SIL
LY1D-2-5S-AC120
LY2-US-AC240
LY3-UA-DC24

00576P0020
00600P0010
LZN4-UA-DC12
LZNQ2M-US-DC5
LZNQ2-US-DC12
LZP40N10
00-8196-RDPP
00-8274-RDPP
00-8275 

RDNP
00-8722-RDPP
00-8728-WHPP
00-9051-RDPP
00-9091-LRPP
00-9291-RDPP
0207100000
0207400000
60100564

01312
0134220000
60713816
M15730061
61161-90
61278-0020
6131-205-17149P
6131-209-15149P
6131-218-17149P

6131-220-21149P
6131-260-2358P
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0
0</t